

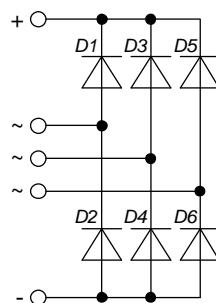
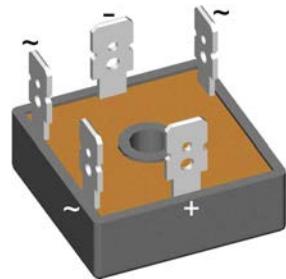
# Standard Rectifier Module

3~ Rectifier
$V_{RRM} = 1600 \text{ V}$
$I_{DAV} = 27 \text{ A}$
$I_{FSM} = 550 \text{ A}$

## 3~ Rectifier Bridge

Part number

**VUO36-16NO8**



 E72873

### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

### Applications:

- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Package: FO-B

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- 1/4" fast-on terminals
- Easy to mount with one screw

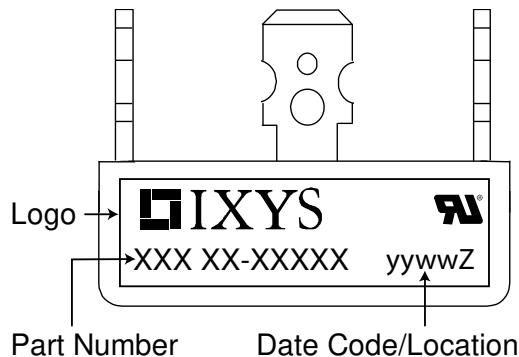
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**Rectifier**

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$V_{RSM}$	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ C$			1700	V
$V_{RRM}$	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ C$			1600	V
$I_R$	reverse current	$V_R = 1600 V$ $V_R = 1600 V$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 150^\circ C$		40 1,5	$\mu A$ mA
$V_F$	forward voltage drop	$I_F = 15 A$ $I_F = 45 A$ $I_F = 15 A$ $I_F = 45 A$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		1,04 1,23 0,93 1,18	V V
$I_{DAV}$	bridge output current	$T_C = 85^\circ C$ rectangular $d = \frac{1}{3}$	$T_{VJ} = 150^\circ C$		27	A
$V_{F0}$ $r_F$	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 150^\circ C$		0,76 9,1	V $m\Omega$
$R_{thJC}$	thermal resistance junction to case				7	K/W
$R_{thCH}$	thermal resistance case to heatsink			1		K/W
$P_{tot}$	total power dissipation		$T_C = 25^\circ C$		17	W
$I_{FSM}$	max. forward surge current	$t = 10 ms; (50 Hz)$ , sine $t = 8,3 ms; (60 Hz)$ , sine	$T_{VJ} = 45^\circ C$ $V_R = 0 V$		550 595	A
		$t = 10 ms; (50 Hz)$ , sine $t = 8,3 ms; (60 Hz)$ , sine	$T_{VJ} = 150^\circ C$ $V_R = 0 V$		470 505	A
$I^2t$	value for fusing	$t = 10 ms; (50 Hz)$ , sine $t = 8,3 ms; (60 Hz)$ , sine	$T_{VJ} = 45^\circ C$ $V_R = 0 V$		1,52 1,48	kA <sup>2</sup> s
		$t = 10 ms; (50 Hz)$ , sine $t = 8,3 ms; (60 Hz)$ , sine	$T_{VJ} = 150^\circ C$ $V_R = 0 V$		1,11 1,06	kA <sup>2</sup> s
$C_J$	junction capacitance	$V_R = 400 V; f = 1 MHz$	$T_{VJ} = 25^\circ C$	18		pF

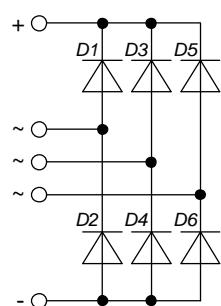
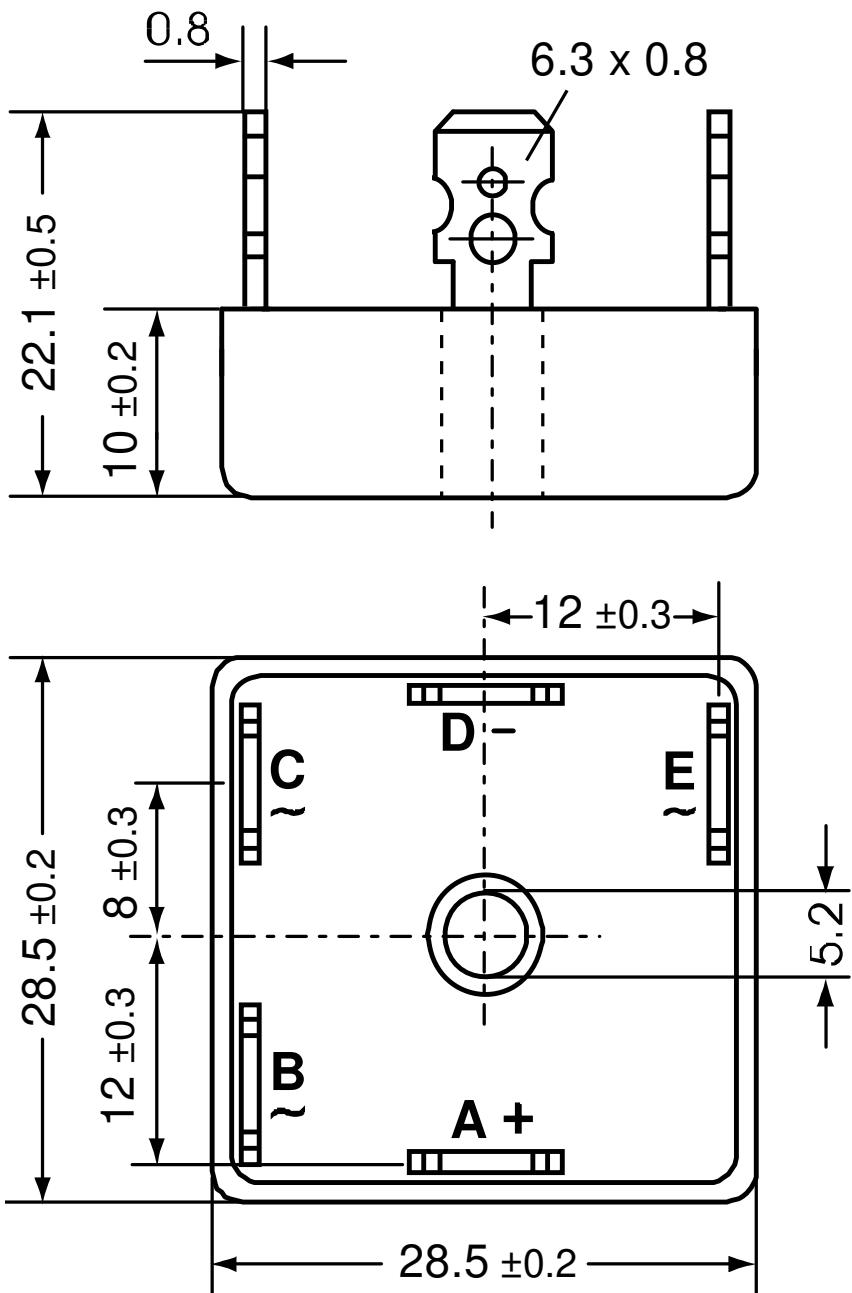
Package FO-B			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal			100	A
$T_{VJ}$	virtual junction temperature		-40		150	°C
$T_{op}$	operation temperature		-40		125	°C
$T_{stg}$	storage temperature		-40		125	°C
<b>Weight</b>				20		g
$M_D$	mounting torque		1,8		2,2	Nm
$d_{Spp/App}$	creepage distance on surface / striking distance through air		terminal to terminal	9,0	7,0	mm
$d_{Spb/Apb}$			terminal to backside	10,0	10,0	mm
$V_{ISOL}$	isolation voltage	t = 1 second t = 1 minute	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA		3000 2500	V V



Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	VUO36-16NO8	VUO36-16NO8	Box	50	465178

**Equivalent Circuits for Simulation**
\* on die level
 $T_{VJ} = 150^\circ\text{C}$ 

	$R_0$	Rectifier	
$V_{0\ max}$	threshold voltage	0,76	V
$R_{0\ max}$	slope resistance *	7,9	$\text{m}\Omega$

**Outlines FO-B**


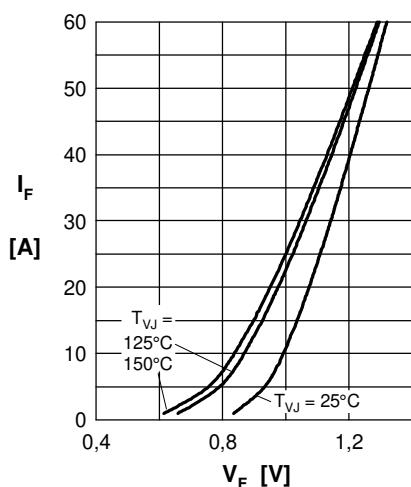
**Rectifier**


Fig. 1 Forward current vs.  
voltage drop per diode

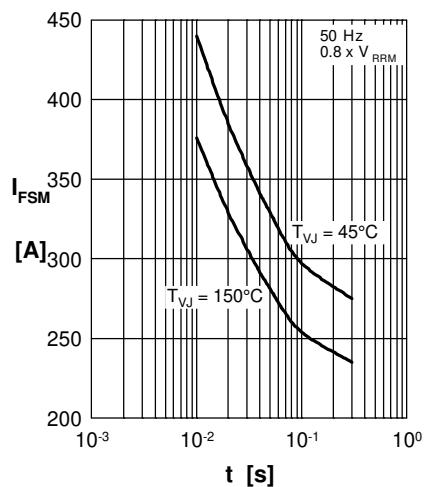


Fig. 2 Surge overload current  
vs. time per diode

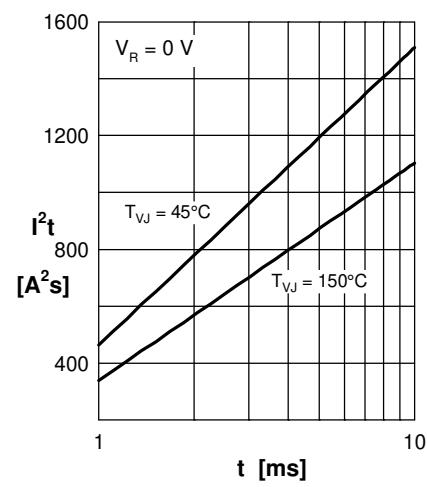


Fig. 3  $I^2t$  vs. time per diode

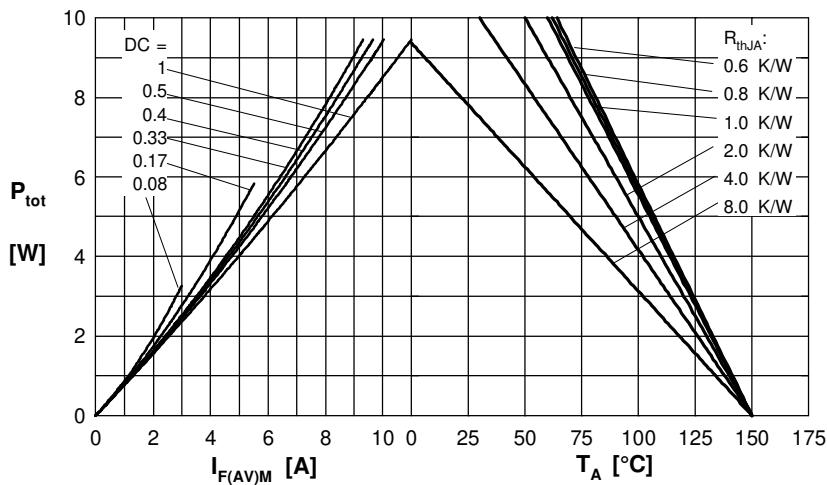


Fig. 4 Power dissipation vs. forward current  
and ambient temperature per diode

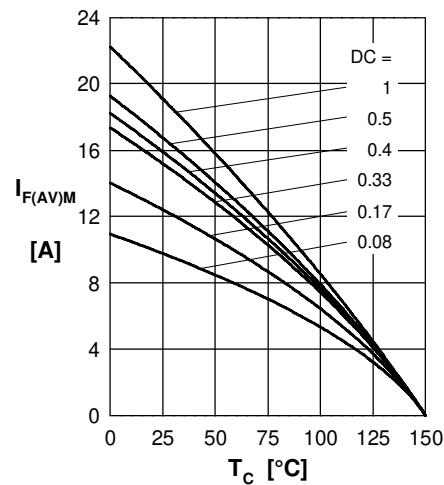


Fig. 5 Max. forward current vs.  
case temperature per diode

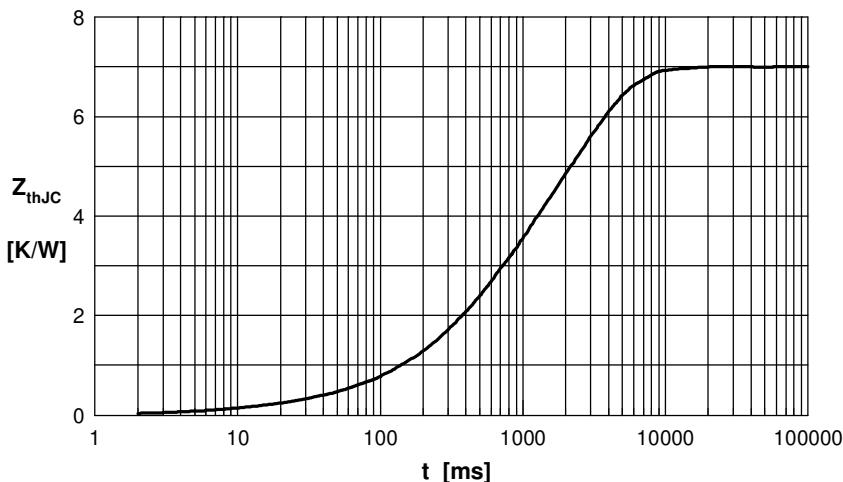


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for  $Z_{thJC}$  calculation:

i	R <sub>th</sub> (K/W)	t <sub>i</sub> (s)
1	0.040	0.005
2	0.150	0.030
3	1.710	0.400
4	5.100	2.300